

A Low-Distortion Output Stage with Improved Stability for Monolithic Power Amplifiers

EVERT SEEVINCK, SENIOR MEMBER, IEEE, WIM DE JAGER, AND PIET BUITENDIJK

Abstract—A new low-distortion class *AB* output stage with improved stability suitable for monolithic power amplifiers ($P_o \geq 40$ W) is described. The concept has been verified on a 12-W breadboard version as well as on a partly integrated prototype, and is supported by computer simulations for $P_o \geq 40$ W. A new biasing control law is implemented which guarantees predictable conduction of both output transistors at all times. This reduces crossover distortion and allows the customary quasi-p-n-p compound transistor to be eliminated, thus also improving stability. Linearity is improved by use of local negative feedback. Phase margin is improved by application of high-frequency feedforward. Measured phase margin is around 60° and total harmonic distortion for a load of 7Ω is about -80 dB at 20 kHz.

I. INTRODUCTION

POWER amplifiers perform a fundamental interfacing function between low-level signal processing circuits and the "real world." An important application area is audio amplifiers where, since the advent of digital signal sources (CD and DAT), the required distortion specification poses a major design challenge. The output stage of power amplifiers has always been a problem in this context, particularly when designed for monolithic realization. Obtaining accurate quiescent current control, low distortion, and adequate high-frequency stability in a standard bipolar process which does not provide high-current p-n-p transistors requires new circuit techniques.

This paper describes a power amplifier design with a new class *AB* output stage which successfully addresses the above-mentioned problems and which is implemented in a standard bipolar process. The amplifier is intended for high output power (≥ 40 W) and features low distortion (THD of -80 dB at 20 kHz) and good stability (phase margin 60°).

The paper is organized as follows. In Section II the problems associated with the classic design approach are discussed. Section III introduces the new improved amplifier principle. Section IV describes a local feedback tech-

nique with high-frequency signal feedforward. Section V presents a new class *AB* biasing technique which guarantees conduction of both output transistors at all times. A complete power amplifier circuit is discussed in Section VI. Experimental circuit realization is the topic of Section VII. The measured results are presented in Section VIII. Finally, conclusions are formulated in Section IX.

II. PROBLEMS OF CLASSIC POWER OUTPUT STAGE DESIGNS

Most presently available integrated power amplifiers conform to the basic op-amp structure as depicted in Fig. 1 [1].

The required high-current p-n-p transistor in the output stage is synthesized from a combination of a small p-n-p transistor Q_3 and a large n-p-n transistor Q_2 . However, this "quasi-p-n-p" compound transistor is unsuitable for high currents unless special measures are taken [1]–[4]. Its stability properties are best discussed with the aid of Fig. 2, which represents the quasi-p-n-p structure as a feedback amplifier [5].

The open-loop response of the circuit model of Fig. 2 has two poles due to the parasitic capacitances C_1 and C_2 . In addition, the lateral p-n-p transistor contributes a phase shift; together this results in negative phase margin when closing the loop (dotted line). This explains the persistent local parasitic oscillations produced by the quasi-p-n-p structure, particularly at high current when the p-n-p transistor has a high transconductance.

A second problem associated with classic output stages is nonlinearity caused by V_{BE} variations of the output emitter followers which pass the large output currents (up to 4 A). Referring to Fig. 1, the signal transfer to node N is quite linear. However, the nonlinear V_{BE} variations of Q_1 and Q_3 pollute the signal when it is transferred from node N to the output. In the recent past an error compensation technique has been applied which measures the nonlinear error signal and subtracts it from the input signal [4]. In contrast, our present technique, which will be discussed in the next sections, uses local negative feedback to improve the open-loop linearity.

Manuscript received September 3, 1987; revised January 19, 1988.

E. Seevinck is with Philips Research Laboratories, 5600 JA Eindhoven, The Netherlands and with the Faculty of Electrical Engineering, Twente University, 7500 AE Enschede, The Netherlands.

W. de Jager is with the Faculty of Electrical Engineering, Twente University, 7500 AE Enschede, The Netherlands.

P. Buitendijk is with Philips-Elcoma, Nijmegen, The Netherlands.
IEEE Log Number 8820265.